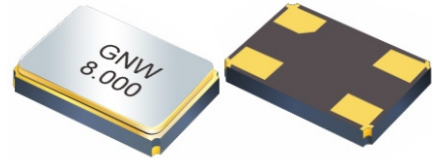


3.2×2.5 SMD Crystal



APPLICATIONS

- Bluetooth / Wireless LAN
- Wearable Devices
- LTE / SAS

FEATURE

- Rugged AT-cut crystal construction
- Miniature 3.2×2.5mm ceramic package
- Anti-EMI design

- Tight Tolerance and Stability
- Reflow Soldering/Emboss Taping



Electrical Specifications 电气参数

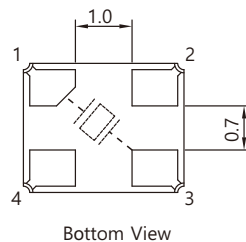
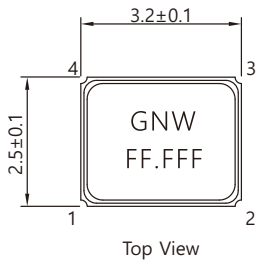
项目	Item/Type	Electrical Specifications
频率范围	Frequency Range	8MHz to 100MHz
调整频差	Frequency Tolerance(ΔF)(at 25°C)	± 10 ppm to ± 30 ppm
温度频差	Frequency Drift	± 10 ppm to ± 30 ppm
工作温度范围	Operating Temperature Range	-20°C ~ +70°C, -40°C ~ +85°C or -40°C ~ +105°C
储存温度范围	Storage Temperature Range	-55°C ~ +125°C
老化	Aging (25°C)	± 3 ppm/year max.
静电容	Shunt Capacitance (C0)	3pF max.
激励功率	Drive Level	10 μ W Typical
绝缘阻抗	Insulation Resistance (Rs)	500 Megaohms min. at D.C 100V
负载电容	Load Capacitance (CL)	8,10,12pF or specify

Equivalent Series Resistance and Mode of Operation 等效阻抗和振荡模式

Frequency Range 频率范围	ESR (Ω) 等效阻抗	Mode 振荡模式
8~12MHz	200 Ω max.	Fundamental
12~16MHz	100 Ω max.	Fundamental
16~20MHz	80 Ω max.	Fundamental
20~24MHz	60 Ω max.	Fundamental
24~64MHz	40 Ω max.	Fundamental
54~100MHz	40 Ω max.	3rd overtone

Mechanical Dimensions 外型尺寸

Units:mm



Pin Connection	
#1,#3	Crystal
#2,#4	GND

